

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	((("438"/\$.ccls.) with source with drain) and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/19 06:45
L2	6	((NAND) with source with drain) and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/19 06:55
L3	6	((("20020149081") or ("6115287") or ("6411548")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/19 06:55
S1	1863	NAND with source with drain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/27 10:19
S2	1359	(NAND with source with drain) and semiconductor and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/19 13:25
S3	31	(NAND with source with drain) and semiconductor and slot and contact and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 10:50
S5	4	(NAND with source with drain) and semiconductor and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/27 10:19
S6	159	((memory adj cell) with source with drain) and semiconductor and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/19 13:24

S7	4	((("20020149081") or ("6115287") or ("6411548") or ("5780338"))). PN.	US-PGPUB; USPAT	OR	OFF	2005/03/24 14:00
S8	0	((memory adj cell) with source with drain) with (single adj mask\$6)) and semiconductor and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/19 13:24
S9	0	(NAND with source with drain with (single adj mask\$6)) and semiconductor and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/19 13:25
S10	0	(NAND with source with drain with (single adj mask\$6)) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/19 13:25
S11	2226	(438/586).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/27 10:19
S12	0	438/586.ccls. and (NAND with source with drain) and semiconductor and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/27 10:20
S13	1	"438"/\$.ccls. and (NAND with source with drain) and semiconductor and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/27 10:20
S14	4	"257"/\$.ccls. and (NAND with source with drain) and semiconductor and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/27 10:24
S15	0	("257"/\$.ccls. with source with drain) and semiconductor and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/27 10:25

S16	0	("438"/\$.ccls. with source with drain) and semiconductor and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/27 10:25
S17	0	((("438"/\$.ccls.) with source with drain) and semiconductor and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/27 10:25
S18	0	((("257"/\$.ccls.) with source with drain) and semiconductor and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/27 10:26
S19	0	((("257"/\$.ccls.) with source with drain) and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/27 10:26
S20	0	((("438"/\$.ccls.) with source with drain) and (single adj mask\$6) and @ad<="20031023"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/19 06:45